

PLASTIC SILICON RECTIFIERS

REVERSE VOLTAGE - 50 to 1000 Volts
FORWARD CURRENT - 4.0 Amperes

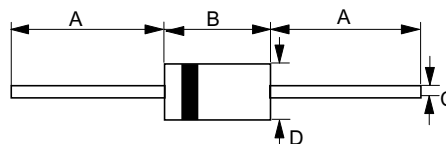
FEATURES

- Low cost
- Diffused junction
- Low forward voltage drop
- Low reverse leakage current
- High current capability
- The plastic material carries UL recognition 94V-0

MECHANICAL DATA

- Case : JEDEC DO-201AD molded plastic
- Polarity : Color band denotes cathode
- Weight : 0.04 ounces, 1.1 grams
- Mounting position : Any

DO-201AD



DO-201AD		
Dim.	Min.	Max.
A	25.4	-
B	7.20	9.50
C	1.20 \varnothing	1.30 \varnothing
D	4.80 \varnothing	5.30 \varnothing
Dimensions in millimeters		

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.
Single phase, half wave, 60Hz, resistive or inductive load.
For capacitive load, derate current by 20%

CHARACTERISTICS	SYMBOL	CT4A01	CT4A02	CT4A03	CT4A04	CT4A05	CT4A06	CT4A07	UNIT
Maximum Recurrent Peak Reverse Voltage	V _{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	V _{RMS}	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	V _{DC}	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current @T _A =60°C	I(AV)	4.0							A
Peak Forward Surge Current 8.3ms single half sine-wave super imposed on rated load (JEDEC Method)	I _{FSM}	210							A
Maximum forward Voltage at 4.0A DC	V _F	1.1							V
Maximum DC Reverse Current at Rated DC Blocking Voltage @T _J =25°C @T _J =100°C	I _R	10 100							uA
Typical Junction Capacitance (Note 1)	C _J	100							pF
Typical Thermal Resistance (Note 2)	R _{θJA/JC}	15/11							°C/W
Operating Temperature Range	T _J	-55 to +150							°C
Storage Temperature Range	T _{STG}	-55 to +150							°C

NOTES : 1.Measured at 1.0MHz and applied reverse voltage of 4.0V DC.
2.Thermal Resistance Junction to Ambient and Junction to Case.

RATINGS AND CHARACTERISTIC CURVES

